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# BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu$ PC78L00 SERIES

## THREE TERMINAL POSITIVE VOLTAGE REGULATORS

#### **DESCRIPTION**

The  $\mu$ PC78L00 series are monolithic three terminal positive regulators which employ internally current limiting, thermal shut down, output transistor safe area protection make them essentially indestructible.

They are intended as fixed voltage regulators in a wide range of application including local on card regulation for elimination of distribution problems associated wide single point regulation.

#### **FEATURES**

- Output current in excess of 100 mA.
- Low noise.
- High Ripple Rejection.
- Internal output transistor safe area protection.
- Internal thermal overload protection.
- Internal short circuit current limiting.

#### ORDER INFORMATION

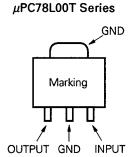
Type Number	Output Voltage	Package	Quality Grade
μPC78L05J		TO-92	
μPC78L05T	5 V	SOT-89	
μPC78L06J		TO-92	
μPC78L06T	6 V	SOT-89	
μPC78L07J	7.14	TO-92	
μPC78L07T	7 V	SOT-89	
μPC78L08J	8 V	TO-92	Standard
μPC78L08T	8 V	SOT-89	
μPC78L10J	10 V	TO-92	
μPC78L10T	10 V	SOT-89	
μPC78L12J	12 V	TO-92	
$\mu$ PC78L12T	12 V	SOT-89	
μPC78L15J	15 V	TO-92	
μPC78L15T	15 V	SOT-89	

#### **CONNECTION DIAGRAM**

Marking

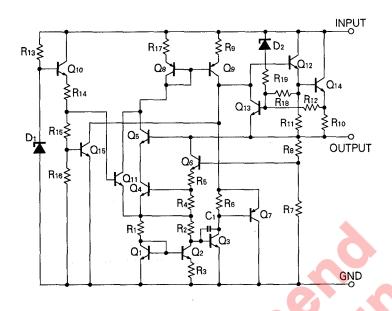
μPC78L00J Series

OUTPUT GND INPUT



Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

## **EQUIVALENT CIRCUIT**



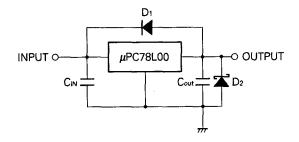
## ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

		RATIN	LIANT	
PARAMETER	SYMBOL	μPC78L00J Series	μPC78L00T Series	UNIT
Input Voltage	Vin	30/35 (Note1)		V
Internal Power Dissipation	Рт	700	400/2000 (Note2)	mW
Operating Ambient Temperature Range	Topt	-20 to +85		°C
Operating Junction Temperature Range	Topt (j)	-20 to +150		°C
Storage Temperature Range	Tstg	-55 to +150		°C
Thermal Resistance (junction to ambient)	Rth (j-a)	180	315/62.5 <sup>(Note2)</sup>	°C/W

(Note 1) µPC78L05, 06, 07, 08 : 30 V, µPC78L10, 12, 15 : 35 V

(Note 2) with 2.5 cm $^2 \times 0.7$  mm ceramic substrate

## **TYPICAL CONNECTION**



C1: Required if regulator is located an appreciable distance from power supply filter

C<sub>2</sub>: More than 0.1  $\mu$ F D<sub>1</sub>: Needed for V<sub>IN</sub> < V<sub>O</sub>

D2: Needed for Vo < GND

## **RECOMMENDED OPERATING CONDITIONS**

CHARACTERISTIC	SYMBOL	TYPE NUMBER	MIN.	TYP.	MAX.	UNIT
		μPC78L05	7	10	20	
		μPC78L06	8.5	11	21	
		μPC78L07	9.5	12	22	
Input Voltage	Vin	μPC78L08	10.5	14	23	V
		μPC78L10	12.5	17	25	
		μPC78L12	14.5	19	27	
		μPC78L15	17.5	23	30	
Output Current	lo	All	0	40	70	mA
Operating Temperature Range	Topt	All	-20		+85	°C
Operating Junction Temperature Range	Topt (j)	All	-20		+125	°C

## ELECTRICAL CHARACTERISTICS $\mu$ PC78L05

(Vin = 10 V, Io = 40 mA, 0 °C  $\leq$  Tj  $\leq$  + 125 °C, Cin = 0.33  $\mu$ F, Cout = 0.1  $\mu$ F)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	4.8	5.0	5.2	
Output Voltage	V <sub>0</sub>	7 V ≦ V <sub>IN</sub> ≦ 20 V, 1 mA ≦ lo ≦ 40 mA	4.75		5.25	] v
		Vin = 10 V, 1 mA ≦ lo ≦ 70 mA	4.75		5.25	]
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 7 V ≦ V <sub>IN</sub> ≦ 20 V		6	150	mV
Emo riogulation	TILON	T <sub>j</sub> = 25 °C, 8 V ≦ V <sub>IN</sub> ≦ 20 V		4	100	
Load Regulation	REGL	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		9	60	mV
Load Regulation	NEGL	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		4	30	] ''''
Quiescent Current	IBIAS	T <sub>i</sub> = 25 °C		2.3	5.5	mA
Quiescent Current Change	⊿IBIAS	8 V ≦ Vin ≦ 20 V, lo = 40 mA			1.5	mA.
	STIRIAS	Vin = 10 V, 1 mA ≦ lo ≦ 40 mA			0.1	1117
Output Noise Voltage	Vn	T <sub>i</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		45	120	μVr.m.s.
Ripple Rejection	R · R	T <sub>j</sub> = 25 °C, f = 120 Hz, 8 V ≦ V <sub>IN</sub> ≦ 18 V	55	75		dB
Dropout Voltage	VDIF	T <sub>i</sub> = 25 °C		1.7		٧
Short Circuit Current	lOshort	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 20 V		88		mA
Peak Output Current	lOpeak	T <sub>i</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	ge ⊿Vo/⊿T	lo = 5 mA		0.4		mV/°C



## ELECTRICAL CHARACTERISTICS $\mu$ PC78L06

(Vin = 11 V, lo = 40 mA, 0 °C  $\leq$  T;  $\leq$  + 125 °C, Cin = 0.33  $\mu$ F, Cout = 0.1  $\mu$ F)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	5.76	6.0	6.24	
Output Voltage	Vo	8.5 V ≦ V <sub>IN</sub> ≦ 21 V, 1 mA ≦ fo ≦ 40 mA	5.70		6.30	v
		V <sub>IN</sub> = 11 V, 1 mA ≦ lo ≦ 70 mA	5.70		6.30	]
	DEC	T <sub>j</sub> = 25 °C, 8.5 V ≦ V <sub>IN</sub> ≦ 21 V		6	155	mV
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 9 V ≦ V <sub>IN</sub> ≦ 21 V		4	105	] ""•
Land Danielation	DEC	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		10	65	mV
Load Regulation	REGL	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		4	35	]
Quiescent Current	IBIAS	T <sub>j</sub> = 25 °C		2.3	5.5	mA
0	∕IBIAS	9 V ≦ Vin ≨ 21 V, lo = 40 mA			1.5	mA
Quiescent Current Change		Vin = 11 V, 1 mA ≦ lo ≦ 40 mA			0.1	] '''`
Output Noise Voltage	Vn	T <sub>j</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		55	145	μVr.m.s.
Ripple Rejection	R · R	Tj = 25 °C, f = 120 Hz, 9 V ≦ ViN ≦ 19 V	54	75		dB
Dropout Voltage	Voif	T <sub>j</sub> = 25 °C		1.7		V
Short Circuit Current	lOshort	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 21 V		85		mA
Peak Output Current	lOpeak	T <sub>i</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.5		mV/°C

## **ELECTRICAL CHARACTERISTICS μPC78L07**

(Vin = 12 V, lo = 40 mA, 0 °C  $\leq$  T;  $\leq$  + 125 °C, Cin = 0.33  $\mu$ F, Cout = 0.1  $\mu$ F)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	6.72	7.0	7.28	
Output Voltage	Vo	9.5 V ≦ Vin ≦ 22 V, 1 mA ≦ io ≦ 40 mA	6.65		7.35	V
	<b>4</b>	V <sub>IN</sub> = 12 V, 1 mA ≦ lo ≦ 70 mA	6.65		7.35	
Line Benedicine	DEC	T <sub>j</sub> = 25 °C, 9.5 V ≦ V <sub>IN</sub> ≦ 22 V		8	165	mV
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 10 V ≦ V <sub>IN</sub> ≦ 22 V		5	115	
Lord Bandation	DEC.	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		12	75	mV
Load Regulation	REGL	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		5	35	
Quiescent Current	IBIAS	T <sub>i</sub> = 25 °C		2.3	5.5	mA
	∄BIAS	10 V ≦ V <sub>IN</sub> ≦ 22 V, lo = 40 mA			1.5	mA
Quiescent Current Change		V <sub>IN</sub> = 12 V, 1 mA ≦ lo ≦ 40 mA			0.1	]
Output Noise Voltage	Vn	T <sub>j</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		70	180	μVr.m.s.
Ripple Rejection	R·R	$T_{j} = 25  ^{\circ}\text{C},  f = 120  \text{Hz},  10  \text{V} \le \text{Vin} \le 20  \text{V}$	52	74		dB
Dropout Voltage	Voif	T <sub>i</sub> = 25 °C		1.7		٧
Short Circuit Current	Oshort	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 22 V		83		mA
Peak Output Current	lOpeak	T <sub>j</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	ΔVο/ΔΤ	lo = 5 mA		0.6		mV/°C

## ELECTRICAL CHARACTERISTICS $\mu$ PC78L08

(Vin = 14 V, Io = 40 mA, 0 °C  $\leq$  T $_{\rm j}$   $\leq$  + 125 °C, Cin = 0.33  $\mu$ F, Cout = 0.1  $\mu$ F)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	7.7	8.0	8.3	
Output Voltage	Vo ·	10.5 V ≦ Vin ≦ 23 V, 1 mA ≦ lo ≦ 40 mA	7.6		8.4	V
		Vin = 14 V, 1 mA ≦ lo ≦ 70 mA	7.6		8.4	
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 10.5 V ≦ V <sub>IN</sub> ≦ 23 V		10	175	mV
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 11 V ≦ V <sub>IN</sub> ≦ 23 V		6	125	
Load Regulation	DEC:	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		14	80	mV
Load Regulation	REGL -	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		6	40	'''V
Quiescent Current	IBIAS	T <sub>i</sub> = 25 °C		2.4	5.5	mA
Quiescent Current Change	∆IBIAS	12 V ≦ Vin ≦ 23 V, lo = 40 mA			1.5	mA
Quiescent current change		Vin = 14 V, 1 mA ≦ lo ≦ 40 mA			0.1	] ""
Output Noise Voltage	Vn	T <sub>j</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		85	190	μVr.m.s.
Ripple Rejection	R·R	T <sub>j</sub> = 25 °C, f = 120 Hz, 12 V ≦ V <sub>IN</sub> ≦ 22 V	51	73		dB
Dropout Voltage	Vdif	T <sub>i</sub> = 25 °C		1.7		٧
Short Circuit Current	lOshort	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 23 V		80		mA
Peak Output Current	lOpeak	T <sub>j</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	<b>∆V</b> o/ <b>∆</b> T	1o = 5 mA		0.6		mV/°C

## ELECTRICAL CHARACTERISTICS µPC78L10

(Vin = 17 V, Io = 40 mA, 0 °C  $\leq$  T<sub>j</sub>  $\leq$  + 125 °C, Cin = 0.33  $\mu$ F, Cout = 0.1  $\mu$ F)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	9.6	10	10.4	
Output Voltage	Vo	12.5 V ≦ Vın ≦ 25 V, 1 mA ≦ lo ≦ 40 mA	9.5		10.5	v
		Vin = 17 V, 1 mA ≦ lo ≦ 70 mA	9.5		10.5	]
Line Regulation	REGIN	T <sub>i</sub> = 25 °C, 12.5 V ≦ V <sub>IN</sub> ≦ 25 V		12	200	mV
Line negulation	NEGIN	Tj = 25 °C, 13 V ≦ Vin ≦ 25 V		8	150	] ""
Load Regulation	REG∟	T <sub>i</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		18	90	mV
	REGL	T <sub>i</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		8	45	1111
Quiescent Current	İBIAS	T <sub>j</sub> = 25 °C		2.5	5.5	mA
Quiescent Current Change	∆ÎBIAS	13 V ≦ Vin ≦ 25 V, lo = 40 mA			1.5	mA
Culescent Current Change		V <sub>IN</sub> = 17 V, 1 mA ≦ lo ≦ 40 mA			0.1	1 1110
Output Noise Voltage	Vn	T <sub>j</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		100	230	μVr.m.s.
Ripple Rejection	R·R	Tj = 25 °C, f = 120 Hz, 14 V ≤ Vin ≤ 24 V	49	69		dB
Dropout Voltage	VDIF	T <sub>j</sub> = 25 °C		1.7		٧
Short Circuit Current	lOshort	Tj = 25 °C, Vin = 25 V		70		mA
Peak Output Current	lOpeak	T <sub>j</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	<b>∆Vo/∆</b> T	lo = 5 mA		0.8		mV/°C

## ELECTRICAL CHARACTERISTICS $\mu$ PC78L12

(Vin = 19 V, lo = 40 mA, 0 °C  $\leq$  Tj  $\leq$  + 125 °C, Cin = 0.33  $\mu\text{F}$ , Cout = 0.1  $\mu\text{F}$ )

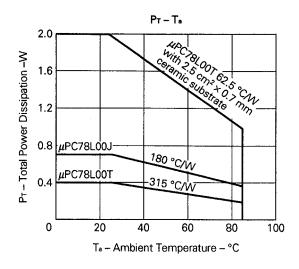
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	11.5	12	12.5	
Output Voltage	Vo	14 V ≦ V <sub>IN</sub> ≦ 27 V, 1 mA ≦ lo ≦ 40 mA	11.4		12.6	] v
		V <sub>IN</sub> = 19 V, 1 mA ≦ lo ≦ 70 mA	11.4		12.6	
	550	T <sub>j</sub> = 25 °C, 14.5 V ≦ V <sub>IN</sub> ≦ 27 V		14	250	mV
Line Regulation	REGIN	Tj = 25 °C, 16 V ≦ VIN ≦ 27 V		10	200	
	250	T <sub>i</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		20	100	mV
Load Regulation	REGL	T <sub>i</sub> = 25 °C, 1 mA ≦ lo ≦ 40 mA		10	50	
Quiescent Current	BIAS	T <sub>j</sub> = 25 °C		2.6	5.5	mA
	ΔIBIAS	16 V ≦ V <sub>IN</sub> ≦ 27 V, lo = 40 mA			1.5	- mA
Quiescent Current Change		V <sub>IN</sub> = 19 V, 1 mA ≦ lo ≦ 40 mA			0.1	
Output Noise Voltage	Vn	T <sub>i</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		115	280	μVr.m.s.
Ripple Rejection	R·R	T <sub>j</sub> = 25 °C, f = 120 Hz, 15 V ≦ V <sub>IN</sub> ≦ 25 V	47	66		dB
Dropout Voltage	VDIF	T <sub>j</sub> = 25 °C		1.7		V
Short Circuit Current	lOshort	T <sub>i</sub> = 25 °C, V <sub>IN</sub> = 27 V		64		mA
Peak Output Current	lOpeak	T <sub>j</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	<b>∆Vo/∆T</b>	lo = 5 mA		1.1		mV/°C

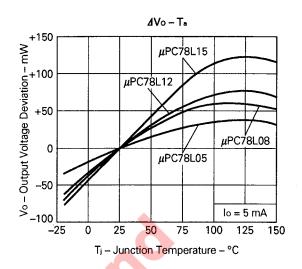
## ELECTRICAL CHARACTERISTICS μPC78L15

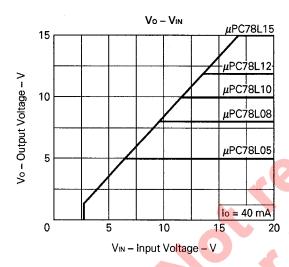
(VIN = 23 V, Io = 40 mA, 0 °C  $\leq$  T<sub>j</sub>  $\leq$  + 125 °C, CIN = 0.33  $\mu$ F, COUT = 0.1  $\mu$ F)

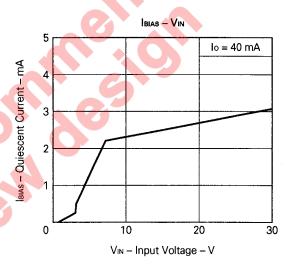
CHARACTERISTIC	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
		T <sub>i</sub> = 25 °C	14.4	15	15.6	
Output Voltage	Vo	17.5 V ≦ Vin ≦ 30 V, 1 mA ≦ lo ≦ 40 mA	14.25		15.75	v
		V <sub>IN</sub> = 23 V, 1 mA ≦ lo ≦ 70 mA	14.25		15.75	
	DEC	T <sub>j</sub> = 25 °C, 17.5 V ≦ V <sub>IN</sub> ≦ 30 V		18	300	mV
Line Regulation	REGIN	T <sub>j</sub> = 25 °C, 20 V ≦ V <sub>IN</sub> ≦ 30 V		13	250	
	DE0	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≦ 100 mA		25	150	mV
Load Regulation	REG∟	T <sub>j</sub> = 25 °C, 1 mA ≦ lo ≨ 40 mA		12	75	
Quiescent Current	BIAS	IBIAS T <sub>i</sub> = 25 °C		2.7	5.5	mA
	∕IIBIAS	20 V ≦ Vin ≦ 30 V, lo = 40 mA			1.5	mA
Quiescent Current Change		V <sub>IN</sub> = 23 V, 1 mA ≦ lo ≦ 40 mA			0.1	
Output Noise Voltage	Vn	T <sub>j</sub> = 25 °C, 10 Hz ≦ f ≦ 100 kHz		135	350	μVr.m.s.
Ripple Rejection	R · R	$T_j = 25$ °C, $f = 120$ Hz, $18.5$ V $\leq$ Vin $\leq 28.5$ V	45	61		dB
Dropout Voltage	VDIF	T <sub>i</sub> = 25 °C		1.7		V
Short Circuit Current	lOshort	T <sub>j</sub> = 25 °C, V <sub>IN</sub> = 30 V		53		mA
Peak Output Current	lOpeak	T <sub>i</sub> = 25 °C	125	160	205	mA
Temperature coefficient of Output Voltage	<b>∆Vo/∆</b> T	lo = 5 mA		1.4		mV/°C

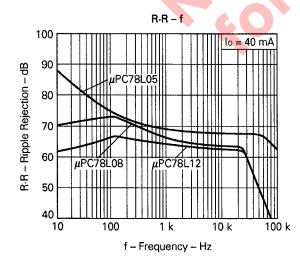
## TYPICAL CHARACTERISTICS (Ta = 25 °C)

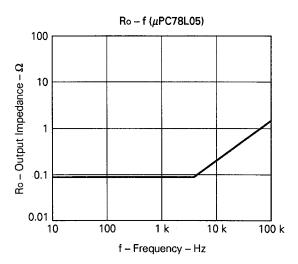


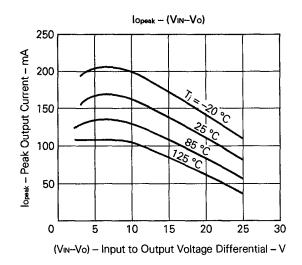


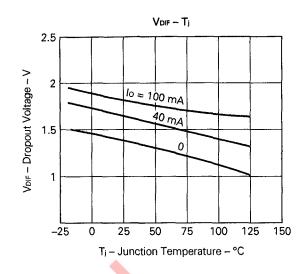


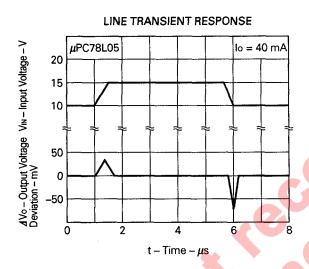


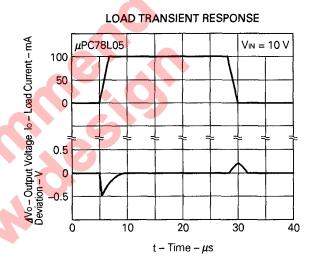






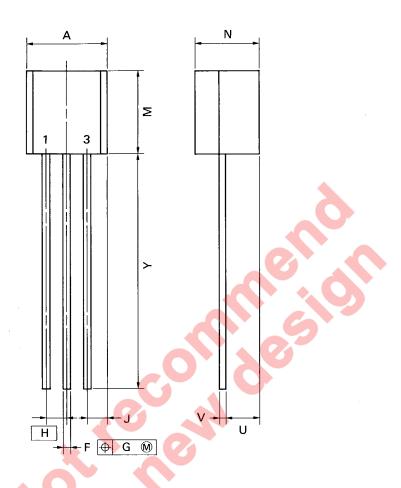






## **PACKAGE DIMENSIONS (Unit: mm)**

 $\mu$ PC78L00J Series 3 PIN PLASTIC SIP (TO-92)



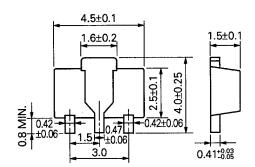
#### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

P3J-127B

ITEM	MILLIMETERS	INCHES
Α	5.2 MAX.	0.205 MAX.
F	0.5 +8.3	0.02 - 8.002
G	0.12	0.005
Н	1.27	0.05
J	1.33 MAX.	0.053 MAX.
М	5.5 MAX.	0.217 MAX.
N	4.2 MAX.	0.166 MAX.
U	2.8 MAX.	0.111 MAX.
V	0.5 <sup>±0.1</sup>	0.02 - 0.004
Υ	15.0 <sup>±0.7</sup>	0.591 + 0.028

 $\mu$ PC78L00T Series





#### **RECOMMENDED SOLDERING CONDITIONS**

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

## <TYPES OF SURFACE MOUNT DEVICE>

For more details, refer to our document "SMT MANUAL" (IEI–1207).  $[\mu PC78L00T Series]$ 

Soldering process	Soldering condition	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-00
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15-00

<sup>\*:</sup> Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25 °C and relative humidity at 65% or less.

Note: Do not apply more than a single process at once, except for "Partial heating method".

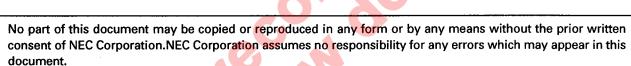
## <TYPES OF THROUGH HOLE MOUNT DEVICE>

[µPC78L00J Series]

Soldering process	Soldering condition	Symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

#### Reference

Application note name	No.
Quality control of NEC semiconductor devices	TEI-1202
Quality control guide of semiconductor devices	MEI-1202
Assembly manual of semiconductor devices	IEI-1207
NEC semiconductor device reliability/quality control system	IEI-1212



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Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

M4 92.6

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